



20 V, N-channel Trench MOSFET 16 February 2021

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Extended temperature range T_i = 175 °C •
- Trench MOSFET technology
- Very fast switching
- ElectroStatic Discharge (ESD) protection > 2 kV HBM (class H2)
- AEC-Q101 gualified

3. Applications

- DC to DC conversion
- High-speed line driver •
- Low-side load switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	20	V
V _{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	-	7.3	А
Static characte	eristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 7.3 A; T _j = 25 °C		-	13	17	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

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5. Pinning information

Table 2. I	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain		G G S 017aaa255

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PMV13XNEA	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PMV13XNEA	XQ%

[1] % = placeholder for manufacturing site code

PMV13XNEA

8. Limiting values

Table 5. Limiting values

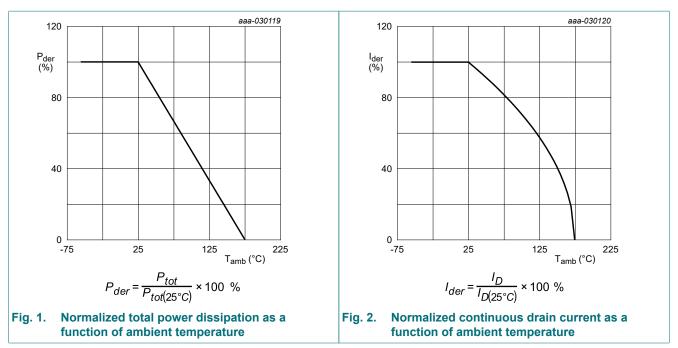
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	7.3	Α
		V _{GS} = 4.5 V; T _{amb} = 100 °C	[1]	-	4.6	Α
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	30	Α
P _{tot} total	total power dissipation	T _{amb} = 25 °C	[2]	-	610	mW
			[1]	-	1.4	W
		T _{sp} = 25 °C		-	8.3	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drain	diode					
Is	source current	T _{amb} = 25 °C	[1]	-	1.4	А
ESD maximu	m rating					
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V
Avalanche ru	ggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$T_{j(init)} = 25 \text{ °C; } I_D = 1.3 \text{ A; DUT in}$ avalanche (unclamped)		-	13	mJ

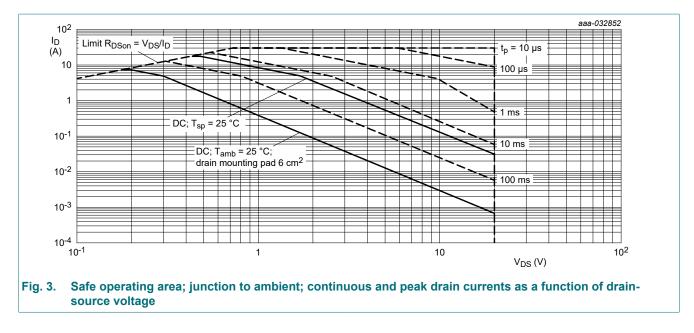
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.



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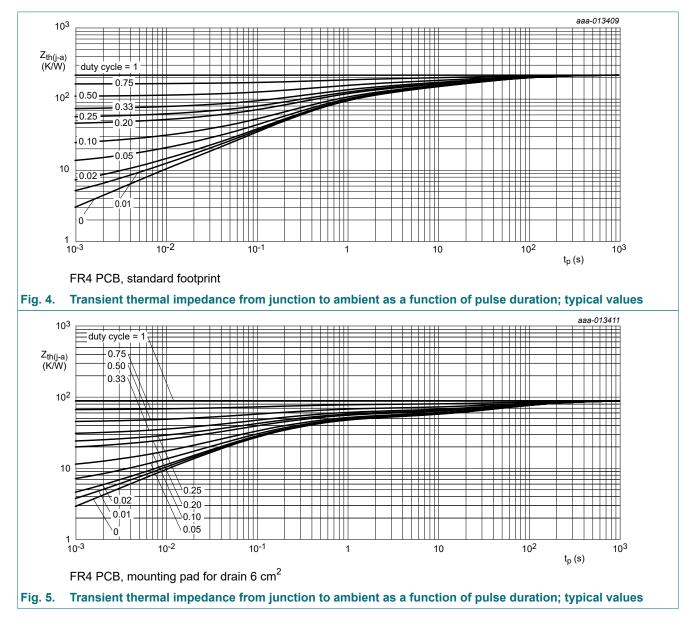


9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from	om in free air	[1]	-	208	245	K/W	
	junction to ambient		[2]	-	88	104	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	13	18	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

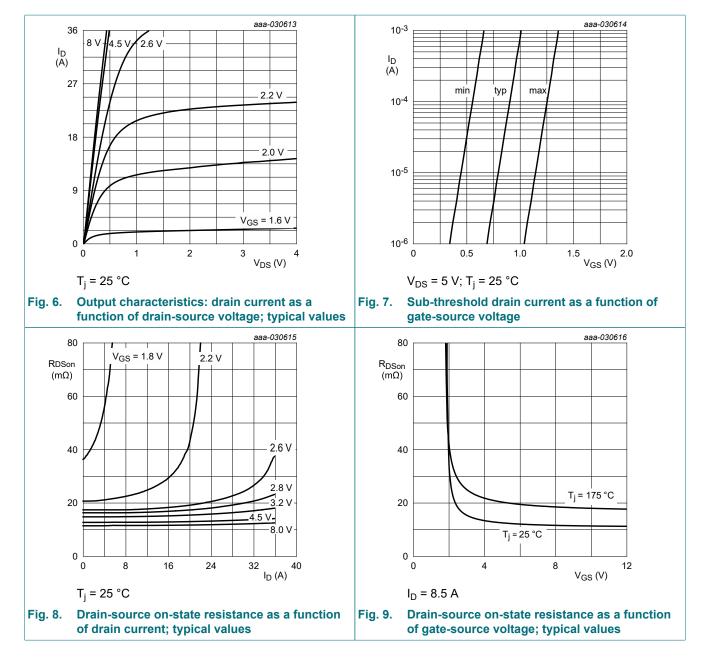
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



10. Characteristics

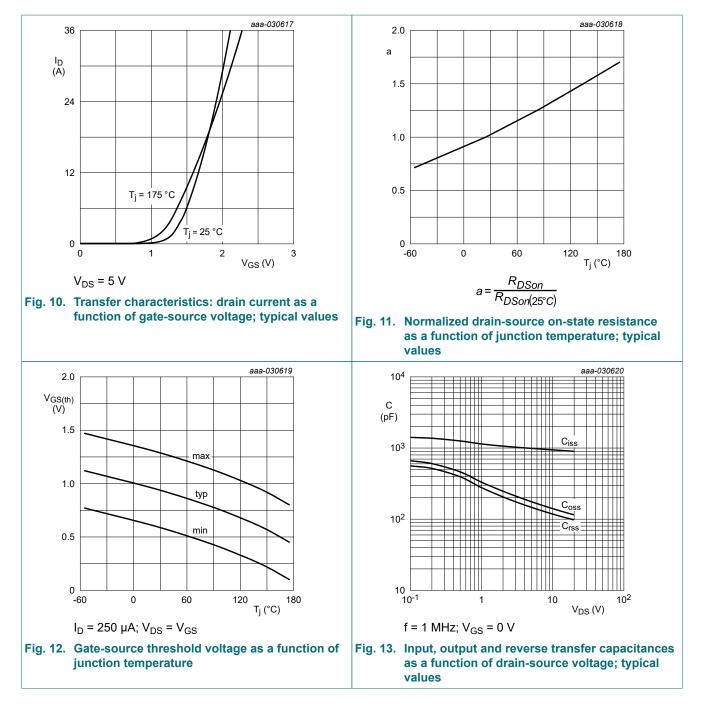
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	0.6	0.95	1.3	V
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V _{GS} = -12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	2	μA
		V _{GS} = -4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-2	μA
R _{DSon} drain-source on-state resistance	drain-source on-state	V _{GS} = 8 V; I _D = 7.3 A; T _j = 25 °C	-	11	15	mΩ
	resistance	V _{GS} = 8 V; I _D = 7.3 A; T _j = 175 °C	-	19	26	mΩ
		V _{GS} = 4.5 V; I _D = 7.3 A; T _j = 25 °C	-	13	17	mΩ
	V _{GS} = 2.5 V; I _D = 2 A; T _j = 25 °C	-	17	25	mΩ	
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 8.5 A; T _j = 25 °C	-	14.4	-	S
R _G	gate resistance	f = 1 MHz	-	1.4	-	Ω
Dynamic ch	aracteristics	· · · ·	I			
Q _{G(tot)}	total gate charge	V_{DS} = 10 V; I _D = 9 A; V _{GS} = 4.5 V;	-	9.8	15	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.5	-	nC
Q _{GD}	gate-drain charge	-	-	2.9	-	nC
C _{iss}	input capacitance	V _{DS} = 10 V; f = 1 MHz; V _{GS} = 0 V;	-	931	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	144	-	pF
C _{rss}	reverse transfer capacitance		-	121	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 10 \text{ V}; I_D = 9 \text{ A}; V_{GS} = 4.5 \text{ V};$	-	4	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	7	-	ns
t _{d(off)}	turn-off delay time	-	-	15	-	ns
t _f	fall time	1	-	9	-	ns
Source-drai	n diode	· · · · ·	I			
V _{SD}	source-drain voltage	I _S = 1.4 A; V _{GS} = 0 V; T _j = 25 °C	-	0.7	1.2	V
t _{rr}	reverse recovery time	I _S = 2 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V;	-	10	-	ns
Q _r	recovered charge	V _{DS} = 10 V; T _j = 25 °C	-	3		nC

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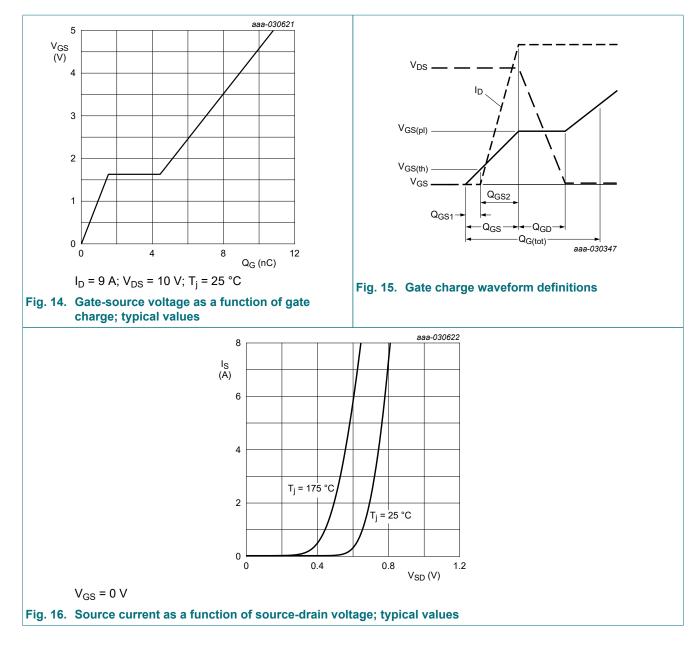
Product data sheet

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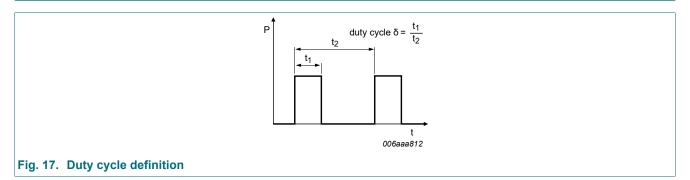


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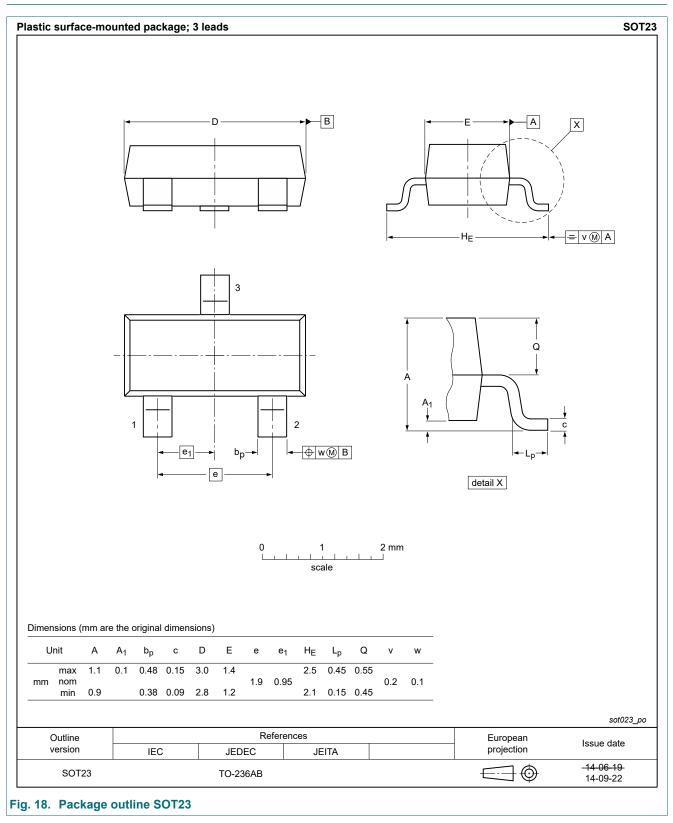
11. Test information



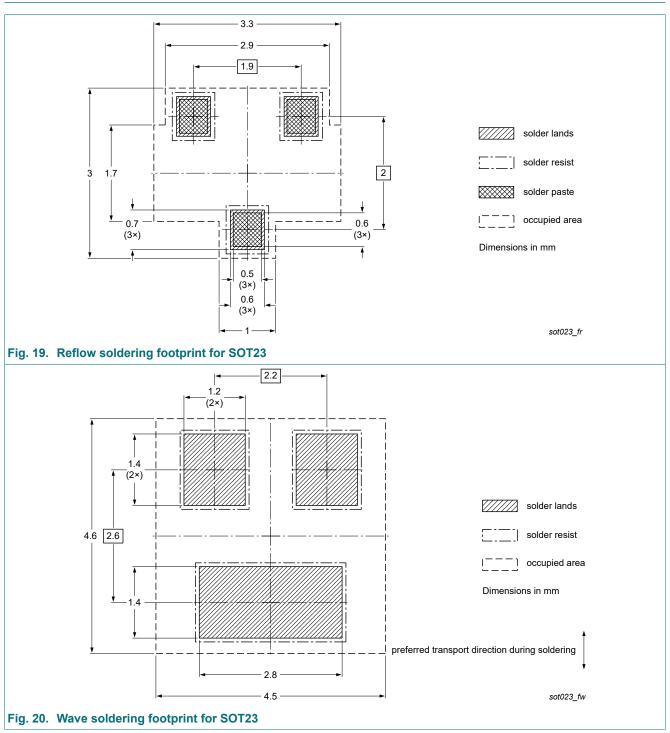
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMV13XNEA v.1	20210216	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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